NSN 5962-01-296-2266

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View Online at https://aerobasegroup.com/nsn/5962-01-296-2266

View Offiline at https://derobasegroup.com/risin/5502-01-250-2250
Body Length:
Between 0.420 inches and 0.440 inches
Body Width:
Between 0.280 inches and 0.305 inches
Body Height:
Between 0.060 inches and 0.120 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and monolithic and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
17 input
Case Outline Source And Designator:
C-13 mil-m-38510
Current Rating Per Characteristic:
50.00 milliamperes forward current, nonrepetitive, peak total value minor
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 leadless
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

Yes - demil/mli

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